

## **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

The NCEP85T25 uses Super Trench technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

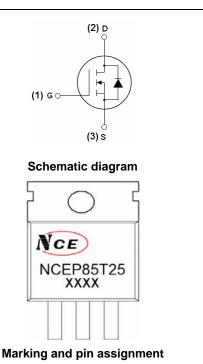
- V<sub>DS</sub> =85V,I<sub>D</sub> =250A  $R_{DS(ON)}$  <2.8m $\Omega$  @  $V_{GS}$ =10V
- Excellent gate charge x R<sub>DS(on)</sub> product
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

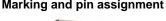
#### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED!

100% AVds TESTED!







TO-220-3L top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP85T25	NCEP85T25	TO-220-3L	-	-	-

Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	85	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	250	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	180	Α
Pulsed Drain Current	I <sub>DM</sub>	800	Α
Maximum Power Dissipation	P <sub>D</sub>	300	W
Derating factor		2	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1700	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 175	°C



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#### **Thermal Characteristic**

### Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	85		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =85V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.5		4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =100A	-	-	2.8	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =100A	-	90	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -40\/\/ -0\/	-	11500	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =40V, $V_{GS}$ =0V, F=1.0MHz	-	2990	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0lvln2	-	105	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	28	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =40 $V$ , $I_{D}$ =100 $A$	-	73	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}\text{=}10V, R_{G}\text{=}1.6\Omega$	-	86	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	33	-	nS
Total Gate Charge	Qg	\/ -40\/   -400	-	165		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=40V,I_{D}=100A,$	-	56		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	35		nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>F</sub> = I <sub>S</sub>	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	250	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C$ , $I_F = I_S$	-	115		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	320		nC

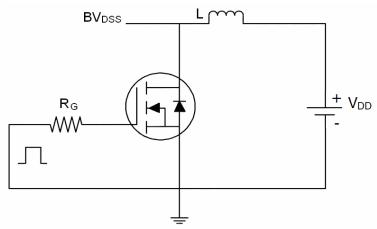
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=42.5V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

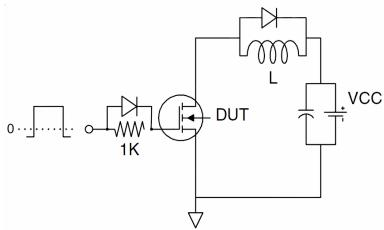


### **Test Circuit**

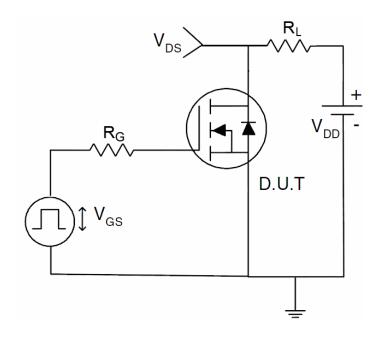
# 1) E<sub>AS</sub> test Circuit



### 2) Gate charge test Circuit

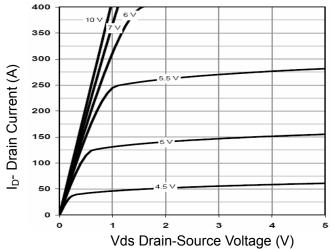


# 3) Switch Time Test Circuit

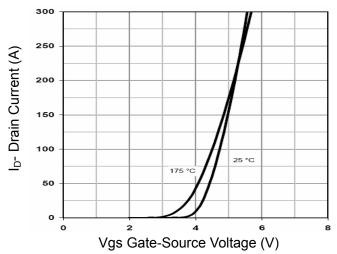








**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

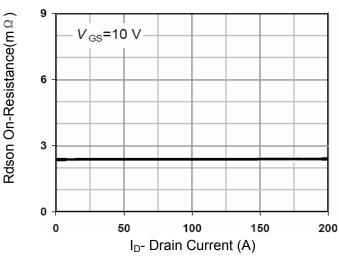


Figure 3 Rdson- Drain Current

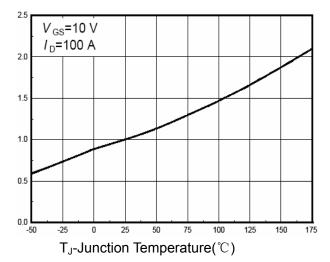


Figure 4 Rdson-JunctionTemperature

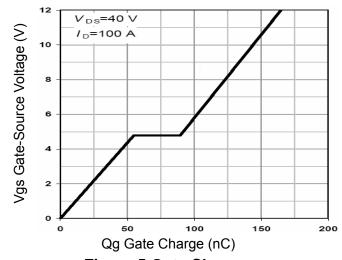


Figure 5 Gate Charge

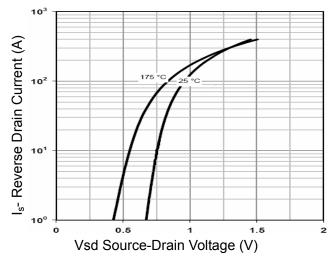
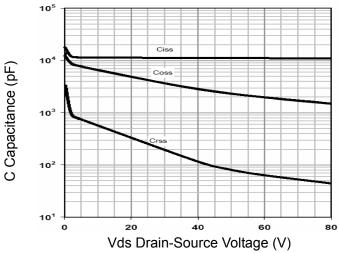


Figure 6 Source- Drain Diode Forward

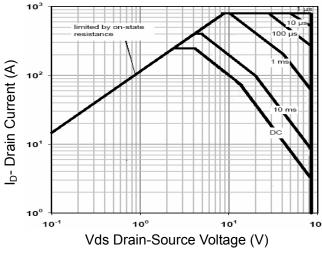


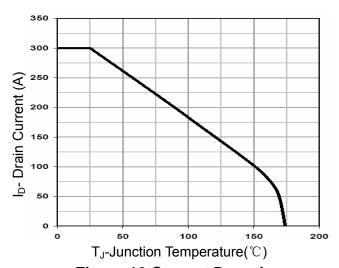


300 (M) 250 200 200 150 150 0 50 100 150 200 TJ-Junction Temperature(°C)

Figure 7 Capacitance vs Vds

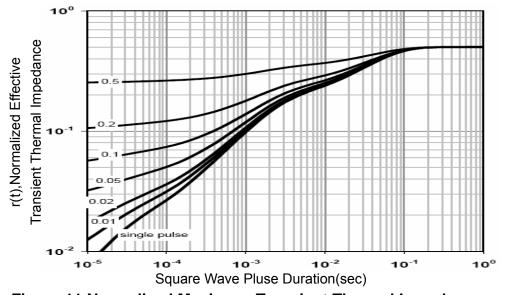
Figure 9 Power De-rating





**Figure 8 Safe Operation Area** 

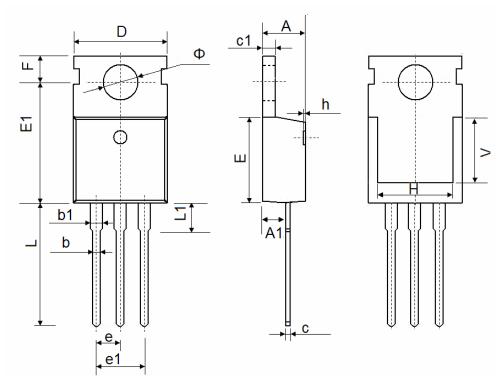
Figure 10 Current De-rating



**Figure 11 Normalized Maximum Transient Thermal Impedance** 

**Pb Free Product** 

# **TO-220-3L Package Information**



Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
Е	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	



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# NCEP85T25

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